



SHENZHEN LONG JING MICRO-ELECTRONICS CO., LTD.

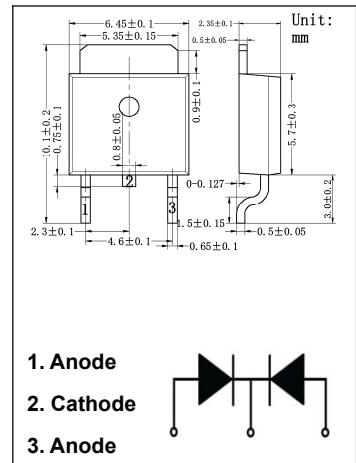
## TO-252 Plastic-Encapsulate RECTIFIER

### **MBRD2045CT**

#### **20A SCHOTTKY BARRIER RECTIFIER**

##### **Features**

- Low power loss, high efficiency.
- High surge capacity
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- Metal silicon junction, majority carrier conduction.
- High current Capability, low forward voltage drop.
- Guard ring for over voltage protection.



##### **Maximum Ratings ( $T_a=25^\circ\text{C}$ unless otherwise specified)**

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-Source voltage	45	V
$V_{RMS}$	Maximum RMS Voltage	31.5	V
$V_{R(DC)}$	Maximum DC Blocking Voltage	45	V
$I_{F(AV)}$	Drain Current	20	A
$I_{FSM}$	Peak Forward Surge Current: 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	200	A
$V_F$	Maximum Forward Voltage @ $I_F=10\text{A}$	0.6	A
$I_R$	Maximum DC Reverse Current $T_j=25^\circ\text{C}$ $T_j=125^\circ\text{C}$	0.02 20	mA
$T_J$	Junction Temperature(MAX)	150	°C
$T_{STG}$	Storage Temperature	-40 to +150	°C

## Typical Characteristics

FIG. 1- FORWARD CURRENT DERATING CURVE

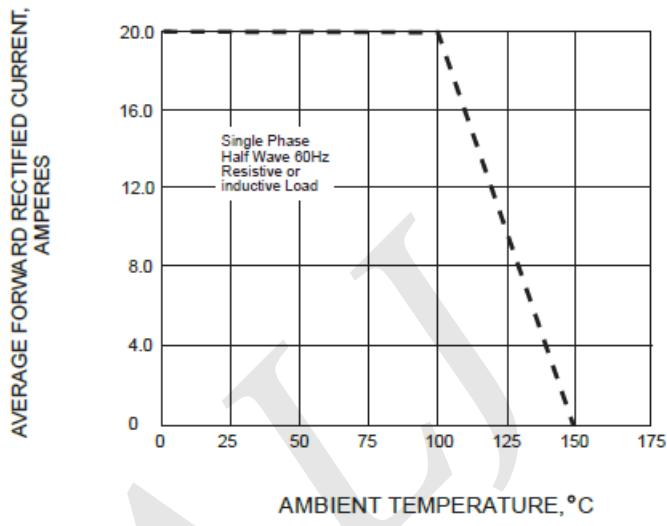


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

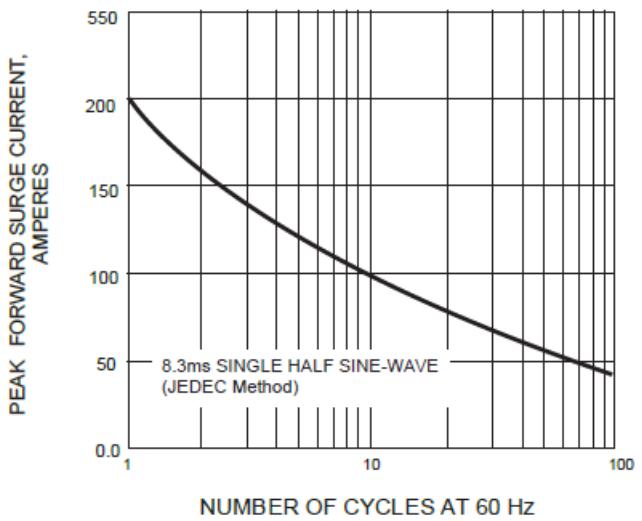


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

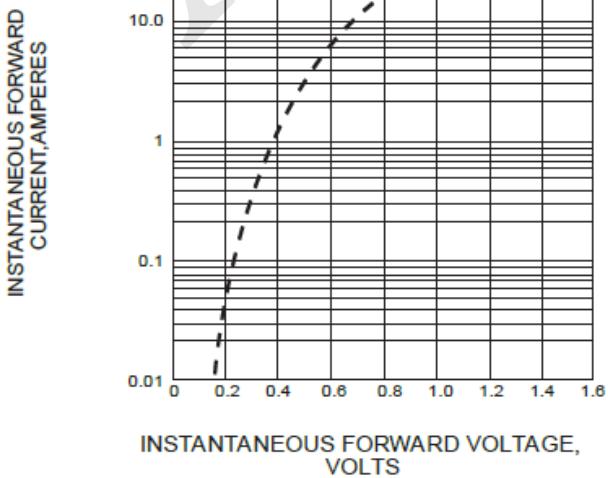


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

